## LIST OF PUBLICATIONS

- Growth and Dislocation Etching of InBi<sub>0.8</sub>Sb<sub>0.2</sub> Single Crystal.
  Cryst. Res. Technol. <u>33</u> 5(1998) 733 736
- Growth of InBi<sub>1-x</sub>Sb<sub>x</sub> Single Crystals Grown by Syringe Pulling Method.
   Proc. Intl. Workshop Prep. & Charact. Tech. Imp. Single Crystals

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(3) Optical Band Gap Of InBi<sub>1-X</sub>Se<sub>X</sub>/Sb<sub>X</sub> (X=0.2,0.3,0.4) Single
 Crystal

Communications In Instrumentation (CIL) (Communicated)